

N-Channel 75 V (D-S) MOSFET

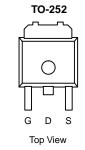
PRODUCT SUMMARY						
V _{(BR)DSS} (V)	r _{DS(on)} (Ω)	I _D (A) ^c	Q _g (Тур.)			
75	0.0068 at V _{GS} = 10 V	75	98 nC			

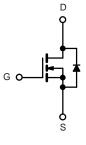
FEATURES

- 175 °C Junction Temperature
- TrenchFET[®] Power MOSFET



• Material categorization:





N-Channel MOSFET

ABSOLUTE MAXIMUM RATINGS ($T_C = 1$	25 °C, unless othe	rwise noted)			
Parameter	Symbol	Limit	Unit		
Gate-Source Voltage	V _{GS}	± 20	V		
Continuous Desig Current (T 475 °C)b	T _C = 25 °C		75		
Continuous Drain Current (T _J = 175 °C) ^b	T _C = 100 °C		70 ^a		
Pulsed Drain Current	I _{DM}	320	А		
Continuous Source Current (Diode Conduction)	۱ _S	70 ^a			
Avalanche Current	I _{AS}	70			
Single Avalanche Energy (Duty Cycle \leq 1 %)	L = 0.1 mH	E _{AS}	300	mJ	
Maximum Dawar Dissinction	T _C = 25 °C	P	140	w	
Maximum Power Dissipation	T _A = 25 °C	• P _D —	3 ^b , 8.3 ^{b, c}		
Operating Junction and Storage Temperature Range		T _J , T _{stg}	- 55 to 175	°C	

THERMAL RESISTANCE RATINGS						
Parameter		Symbol	Typical	Maximum	Unit	
Maximum hungting to Ambient	$t \le 10 \text{ sec}$	R _{thJA}	15	18	°C/W	
Maximum Junction-to-Ambient ^a	Steady State		40	50		
Maximum Junction-to-Case		R _{thJC}	0.85	1.1		

Notes:

a. Package limited.

b. Surface mounted on 1" x 1" FR4 board.

c. $t \leq 10$ s.

DTU75N75

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SPECIFICATIONS ($T_J = 25$	°C, unless o	otherwise noted)					
Parameter	Symbol	Test Conditions	Min.	Typ. ^a	Max.	Unit	
Static			I		<u> </u>		
Drain-Source Breakdown Voltage	V _{DS}	$V_{GS} = 0 V, I_D = 250 \mu A$	75				
Gate Threshold Voltage	V _{GS(th)}	$V_{DS} = V_{GS}, I_D = 250 \ \mu A$	2	3	4	V	
Gate-Body Leakage	I _{GSS}	$V_{DS} = 0 V, V_{GS} = \pm 20 V$			± 100	nA	
		$V_{DS} = 75 \text{ V}, \text{ V}_{GS} = 0 \text{ V}$		1			
Zero Gate Voltage Drain Current	I _{DSS}	$V_{DS} = 60 \text{ V}, \text{ V}_{GS} = 0 \text{ V}, \text{ T}_{J} = 125 \text{ °C}$			10	μA	
		$V_{DS} = 60V, V_{GS} = 0 V, T_{J} = 175 \text{ °C}$			150		
On-State Drain Current ^b	I _{D(on)}	$V_{DS} = 5 V, V_{GS} = 10 V$	75			А	
		V _{GS} = 10 V, I _D = 20 A		0.0068	0.0085		
	R _{DS(on)}	V _{GS} = 10 V, I _D = 20 A, T _J = 125 °C			0.0120		
Drain-Source On-State Resistance ^b		V _{GS} = 10 V, I _D = 20 A, T _J = 175 °C			0.0160	Ω	
Forward Transconductance ^b	9 _{fs}	V _{DS} = 15 V, I _D = 20 A		66		S	
Dynamic	·		·				
Input Capacitance	C _{iss}			2550		pF	
Output Capacitance	C _{oss}	V_{GS} = 0 V, V_{DS} = 25 V, f = 1 MHz		340			
Reverse Transfer Capacitance	C _{rss}			260			
Total Gate Charge ^c	Qg			98	120		
Gate-Source Charge ^c	Q _{gs}	$V_{DS} = 60 \text{ V}, V_{GS} = 10 \text{ V}, I_D = 20 \text{ A}$		20		nC	
Gate-Drain Charge ^c	Q _{gd}			30		1	
Turn-On Delay Time ^c	t _{d(on)}			10	20		
Rise Time ^c	t _r	V_{DD} = 30 V, R_L = 0.6 Ω		18	25	ns	
Turn-Off Delay Time ^c	t _{d(off)}	$I_D \cong 50 \text{ A}, V_{\text{GEN}} = 10 \text{ V}, R_g = 2.5 \Omega$		55	80		
Fall Time ^c	t _f			15	22		
Source-Drain Diode Ratings and Cha	aracteristics (T _C = 25 °C)	·	·	· · ·		
Pulsed Current	I _{SM}				320	А	
Diode Forward Voltage	V _{SD}	I _F = 20 A, V _{GS} = 0 V		1	1.5	V	
Reverse Recovery Time	t _{rr}	I _F = 20 A, di/dt = 100 A/μs		25	36	ns	

Notes:

a. For design aid only; not subject to production testing.

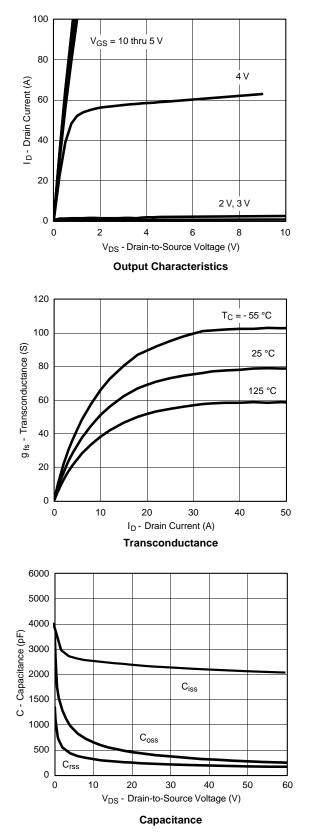
b. Pulse test; pulse width \leq 300 µs, duty cycle \leq 2 %.

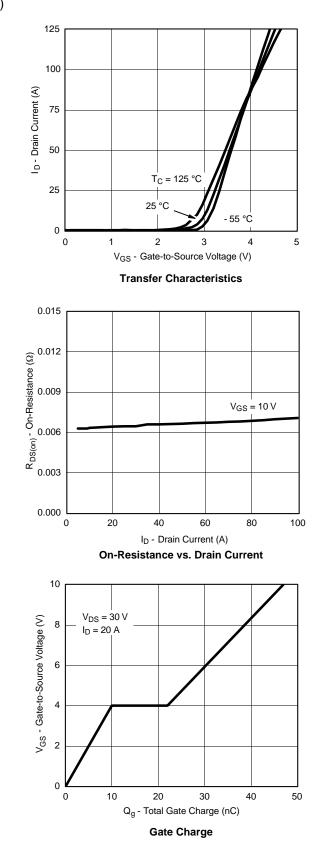
c. Independent of operating temperature.

Stresses beyond those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated in the operational sections of the specifications is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.



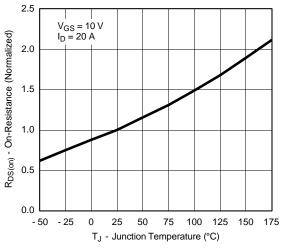
TYPICAL CHARACTERISTICS (25 °C unless noted)



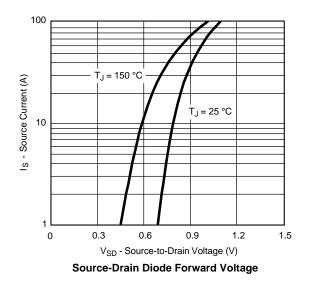




TYPICAL CHARACTERISTICS (25 °C unless noted)

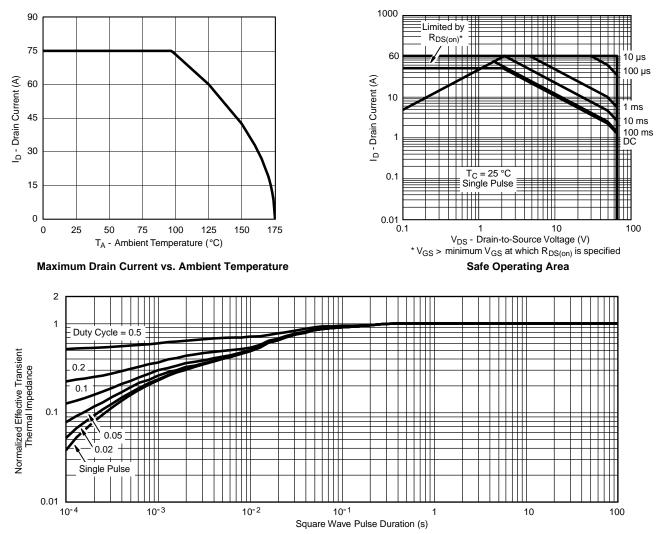


On-Resistance vs. Junction Temperature





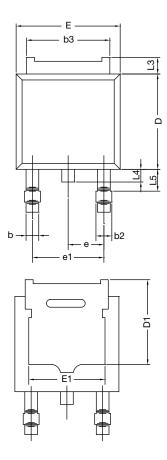
THERMAL RATINGS



Normalized Thermal Transient Impedance, Junction-to-Case









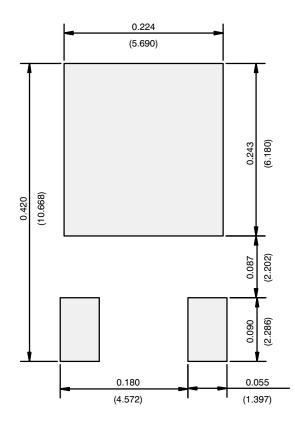
	MILLIN	IETERS	INC	HES	
DIM.	MIN.	MAX.	MIN.	MAX.	
А	2.18	2.38	0.086	0.094	
A1	-	0.127	-	0.005	
b	0.64	0.88	0.025	0.035	
b2	0.76	1.14	0.030	0.045	
b3	4.95	5.46	0.195	0.215	
С	0.46	0.61	0.018	0.024	
C2	0.46	0.89	0.018	0.035	
D	5.97	6.22	0.235	0.245	
D1	5.21	-	0.205	-	
Е	6.35	6.73	0.250	0.265	
E1	4.32	-	0.170	-	
Н	9.40	10.41	0.370	0.410	
е	2.28	BSC	0.090	BSC	
e1	4.56	4.56 BSC		BSC	
L	1.40	1.78	0.055	0.070	
L3	0.89	1.27	0.035	0.050	
L4	-	1.02	-	0.040	
L5	1.14	1.52	0.045	0.060	
ECN: X12-0247-Rev. M, 24-Dec-12 DWG: 5347					

Note

• Dimension L3 is for reference only.



RECOMMENDED MINIMUM PADS FOR DPAK (TO-252)



Recommended Minimum Pads Dimensions in Inches/(mm)

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